

## LM5112 Tiny 7A MOSFET Gate Driver

Check for Samples: [LM5112](#)

### FEATURES

- Compound CMOS and Bipolar Outputs Reduce Output Current Variation
- 7A sink/3A Source Current
- Fast Propagation Times (25 ns Typical)
- Fast Rise and Fall Times (14 ns/12 ns Rise/Fall with 2 nF Load)
- Inverting and Non-inverting Inputs Provide Either Configuration with a Single Device
- Supply Rail Under-voltage Lockout Protection
- Dedicated Input Ground (IN\_REF) for Split Supply or Single Supply Operation
- Power Enhanced 6-pin WSON Package (3.0mm x 3.0mm) or Thermally Enhanced MSOP-PowerPAD Package
- Output Swings from  $V_{CC}$  to  $V_{EE}$  Which can be Negative Relative to Input Ground

### DESCRIPTION

The LM5112 MOSFET gate driver provides high peak gate drive current in the tiny WSON-6 package (SOT-23 equivalent footprint) or an 8-Lead exposed-pad MSOP package, with improved power dissipation required for high frequency operation. The compound output driver stage includes MOS and bipolar transistors operating in parallel that together sink more than 7A peak from capacitive loads. Combining the unique characteristics of MOS and bipolar devices reduces drive current variation with voltage and temperature. Under-voltage lockout protection is provided to prevent damage to the MOSFET due to insufficient gate turn-on voltage. The LM5112 provides both inverting and non-inverting inputs to satisfy requirements for inverting and non-inverting gate drive with a single device type.

### Block Diagram

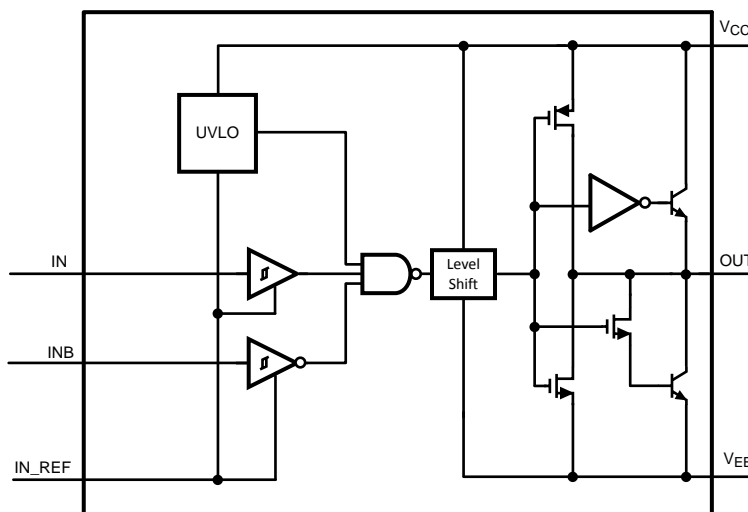


Figure 1. Block Diagram of LM5112



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## Pin Configurations

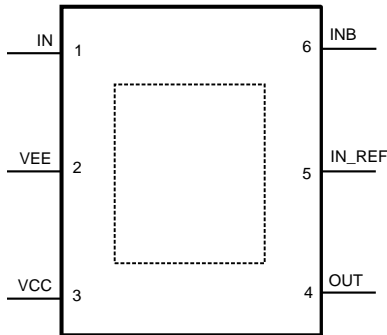


Figure 2. WSON-6

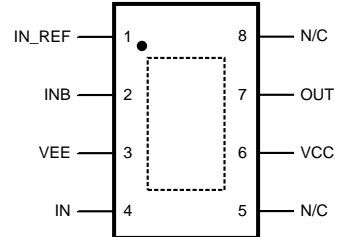


Figure 3. MSOP-PowerPAD-8

### PIN DESCRIPTIONS

Pin		Name	Description	Application Information
WSON-6	MSOP-8			
1	4	IN	Non-inverting input pin	TTL compatible thresholds. Pull up to VCC when not used.
2	3	VEE	Power ground for driver outputs	Connect to either power ground or a negative gate drive supply for positive or negative voltage swing.
3	6	VCC	Positive Supply voltage input	Locally decouple to VEE. The decoupling capacitor should be located close to the chip.
4	7	OUT	Gate drive output	Capable of sourcing 3A and sinking 7A. Voltage swing of this output is from VEE to VCC.
5	1	IN_REF	Ground reference for control inputs	Connect to power ground (VEE) for standard positive only output voltage swing. Connect to system logic ground when VEE is connected to a negative gate drive supply.
6	2	INB	Inverting input pin	TTL compatible thresholds. Connect to IN_REF when not used.
---	5, 8	N/C	Not internally connected	
---	---	Exposed Pad	Exposed Pad, underside of package	Internally bonded to the die substrate. Connect to VEE ground pin for low thermal impedance.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**Absolute Maximum Ratings<sup>(1)(2)</sup>**

$V_{CC}$ to $V_{EE}$	-0.3V to 15V
$V_{CC}$ to IN_REF	-0.3V to 15V
IN/INB to IN_REF	-0.3V to 15V
IN_REF to $V_{EE}$	-0.3V to 5V
Storage Temperature Range	-55°C to +150°C
Maximum Junction Temperature	+150°C
Operating Junction Temperature	-40°C to +125°C
ESD Rating	2kV

- (1) Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions under which operation of the device is intended to be functional. For ensured specifications and test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

**Electrical Characteristics**

$T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ ,  $V_{CC} = 12\text{V}$ , INB = IN\_REF =  $V_{EE} = 0\text{V}$ , No Load on output, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
<b>SUPPLY</b>						
$V_{CC}$	$V_{CC}$ Operating Range	$V_{CC} - \text{IN\_REF}$ and $V_{CC} - V_{EE}$	3.5		14	V
UVLO	$V_{CC}$ Under-voltage Lockout (rising)	$V_{CC} - \text{IN\_REF}$	2.4	3.0	3.5	V
$V_{CCH}$	$V_{CC}$ Under-voltage Hysteresis			230		mV
$I_{CC}$	$V_{CC}$ Supply Current			1.0	2.0	mA
<b>CONTROL INPUTS</b>						
$V_{IH}$	Logic High		2.3			V
$V_{IL}$	Logic Low				0.8	V
$V_{thH}$	High Threshold		1.3	1.75	2.3	V
$V_{thL}$	Low Threshold		0.8	1.35	2.0	V
HYS	Input Hysteresis			400		mV
$I_{IL}$	Input Current Low	IN = INB = 0V	-1	0.1	1	$\mu\text{A}$
$I_{IH}$	Input Current High	IN = INB = $V_{CC}$	-1	0.1	1	$\mu\text{A}$
<b>OUTPUT DRIVER</b>						
$R_{OH}$	Output Resistance High	$I_{OUT} = -10\text{mA}^{(1)}$		30	50	
$R_{OL}$	Output Resistance Low	$I_{OUT} = 10\text{mA}^{(1)}$		1.4	2.5	
$I_{SOURCE}$	Peak Source Current	OUT = $V_{CC}/2$ , 200ns pulsed current		3		A
$I_{SINK}$	Peak Sink Current	OUT = $V_{CC}/2$ , 200ns pulsed current		7		A

- (1) The output resistance specification applies to the MOS device only. The total output current capability is the sum of the MOS and Bipolar devices.



Typical Performance Characteristics

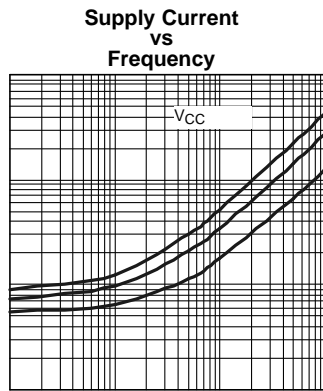


Figure 6.

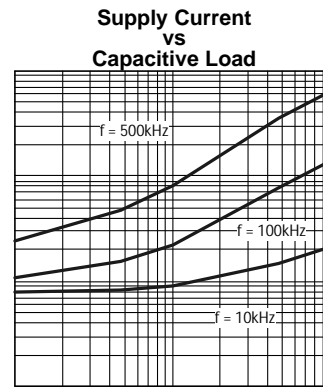


Figure 7.

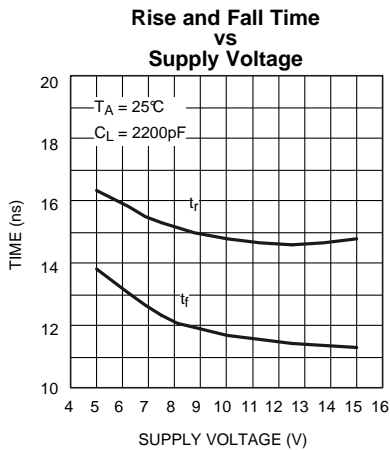


Figure 8.

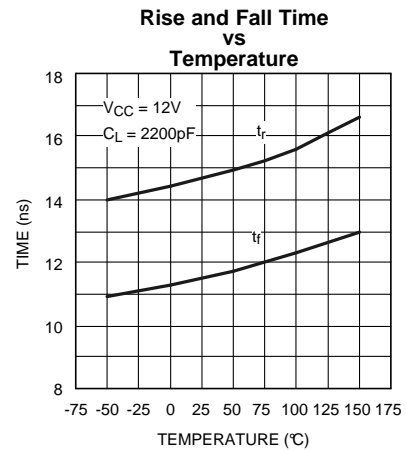


Figure 9.

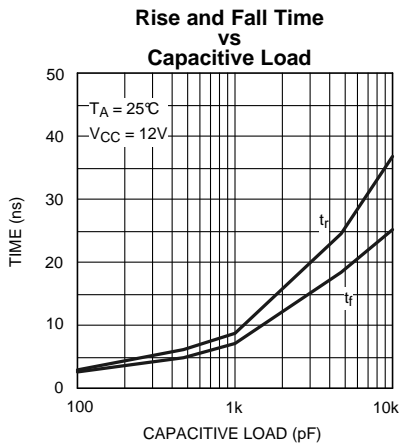


Figure 10.

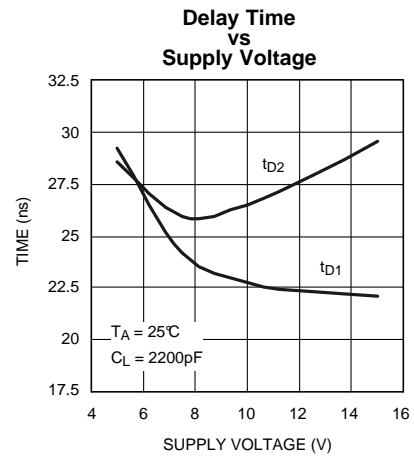


Figure 11.

**Typical Performance Characteristics (continued)**

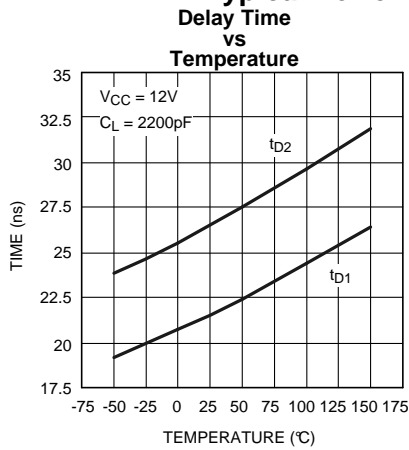


Figure 12.

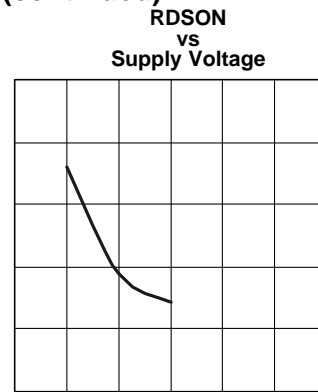


Figure 13.

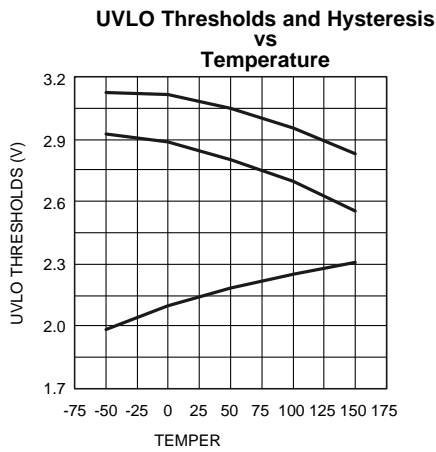


Figure 14.

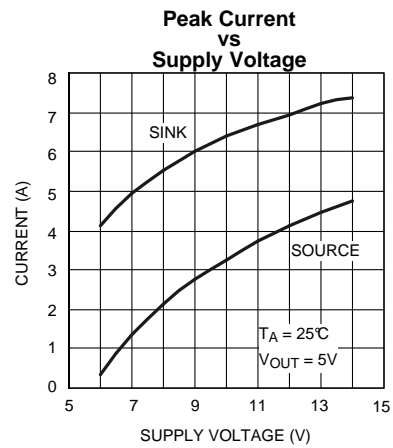


Figure 15.

### Simplified Application Block Diagram

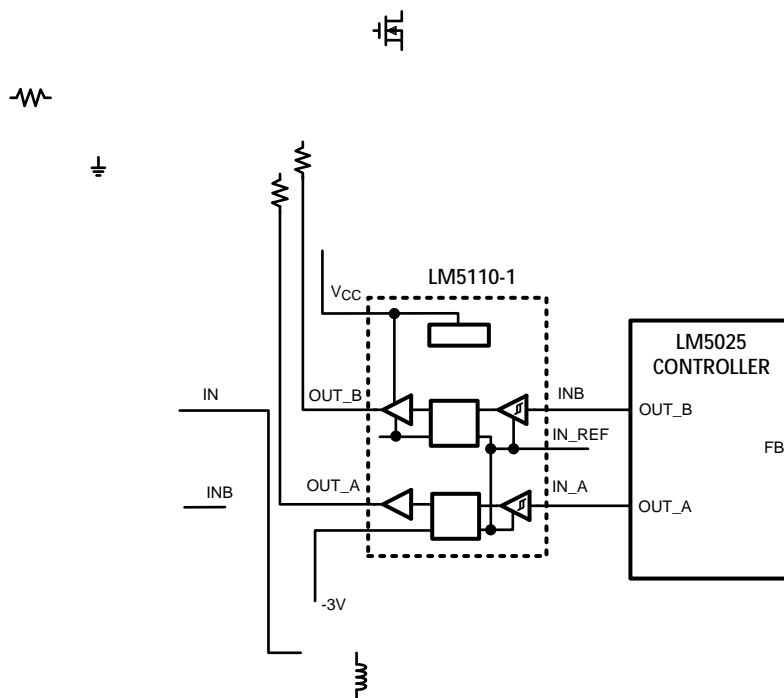
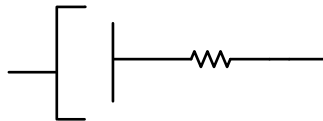


Figure 16. Simplified Application Block Diagram

### DETAILED OPERATING DESCRIPTION

The LM5112 is a high speed , high peak current (7A) single channel MOSFET driver. The high peak output current of the LM5112 will switch power MOSFET's on and off with short rise and fall times, thereby reducing





where

- $F_{SW}$  = switching frequency of the MOSFET (1)

For example, consider the MOSFET MTD6N15 whose gate charge specified as 30 nC for  $V_{GATE} = 12V$ .

Therefore, the power dissipation in the driver due to charging and discharging of MOSFET gate capacitances at switching frequency of 300 kHz and  $V_{GATE}$  of 12V is equal to

$$P_{DRIVER} = 12V \times 30 \text{ nC} \times 300 \text{ kHz} = 0.108W. \quad (2)$$

In addition to the above gate charge power dissipation, - transient power is dissipated in the driver during output transitions. When either output of the LM5112 changes state, current will flow from  $V_{CC}$  to  $V_{EE}$  for a very brief interval of time through the output totem-pole N and P channel MOSFETs. The final component of power dissipation in the driver is the power associated with the quiescent bias current consumed by the driver input stage and Under-voltage lockout sections.

Characterization of the LM5112 provides accurate estimates of the transient and quiescent power dissipation components. At 300 kHz switching frequency and 30 nC load used in the example, the transient power will be 8 mW. The 1 mA nominal quiescent current and 12V  $V_{GATE}$  supply produce a 12 mW typical quiescent power.

Therefore the total power dissipation

$$P_D = 0.118 + 0.008 + 0.012 = 0.138W. \quad (3)$$

We know that the junction temperature is given by

$$T_J = P_D \times \theta_{JA} + T_A \quad (4)$$

Or the rise in temperature is given by

$$T_{RISE} = T_J - T_A = P_D \times \theta_{JA} \quad (5)$$

For WSON-6 package, the integrated circuit die is attached to leadframe die pad which is soldered directly to the printed circuit board. This substantially decreases the junction to ambient thermal resistance ( $\theta_{JA}$ ). By providing suitable means of heat dispersion from the IC to the ambient through exposed copper pad, which can readily dissipate heat to the surroundings,  $\theta_{JA}$  as low as 40°C / Watt is achievable with the package. The resulting Trise for the driver example above is thereby reduced to just 5.5 degrees.

Therefore  $T_{RISE}$  is equal to

$$T_{RISE} = 0.138 \times 40 = 5.5^\circ C \quad (6)$$

For MSOP-PowerPAD  $\theta_{JA}$  is typically 60°C/W.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LM5112MY	ACTIVE	MSOP-PowerPAD	DGN	8	1000	TBD	Call TI	Call TI		SJJB	<a href="#">Samples</a>
LM5112MY/NOPB	ACTIVE	MSOP-PowerPAD	DGN	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		SJJB	<a href="#">Samples</a>
LM5112MYX	ACTIVE	MSOP-PowerPAD	DGN	8	3500	TBD	Call TI	Call TI		SJJB	<a href="#">Samples</a>
LM5112MYX/NOPB	ACTIVE	MSOP-PowerPAD	DGN	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM		SJJB	<a href="#">Samples</a>
LM5112Q1SD/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L250B	<a href="#">Samples</a>
LM5112Q1SDX/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L250B	<a href="#">Samples</a>
LM5112SD	ACTIVE	WSON	NGG	6	1000	TBD	Call TI	Call TI	-40 to 125	L132B	<a href="#">Samples</a>
LM5112SD/NOPB	ACTIVE	WSON	NGG	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L132B	<a href="#">Samples</a>
LM5112SDX	ACTIVE	WSON	NGG	6	4500	TBD	Call TI	Call TI	-40 to 125	L132B	<a href="#">Samples</a>
LM5112SDX/NOPB	ACTIVE	WSON	NGG	6	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	L132B	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.

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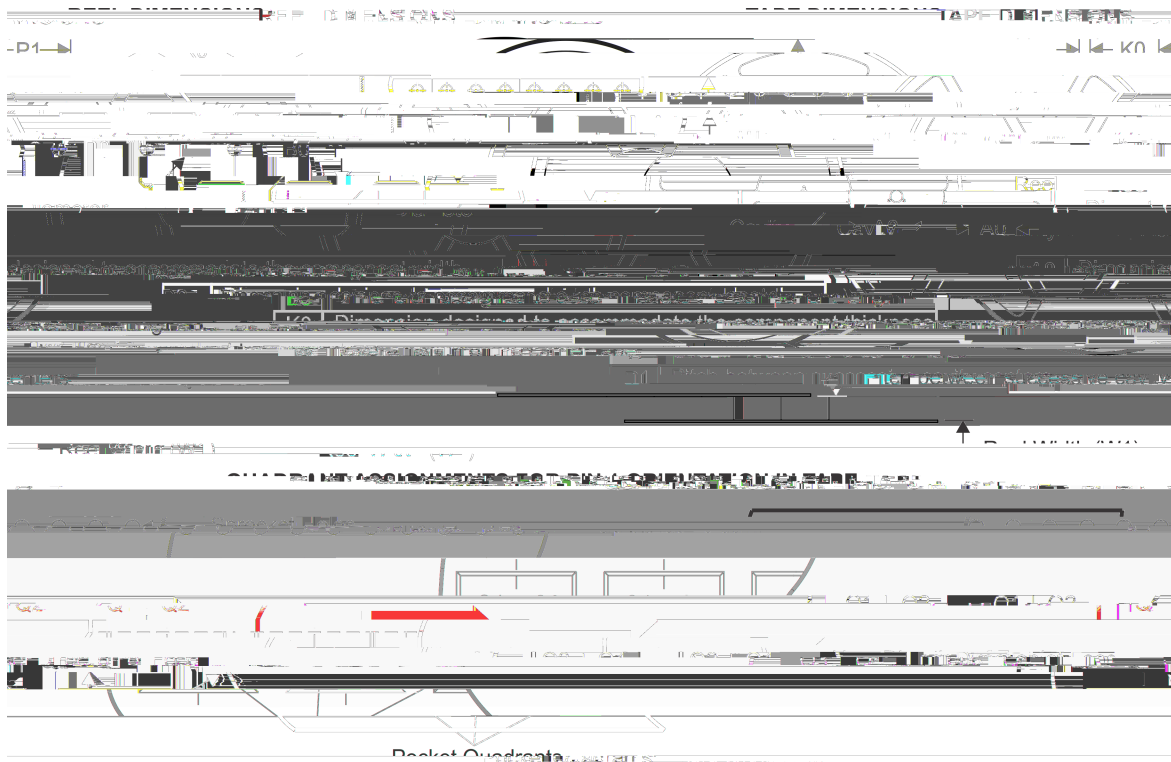
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**OTHER QUALIFIED VERSIONS OF LM5112, LM5112-Q1 :**

- Catalog: [LM5112](#)
- Automotive: [LM5112-Q1](#)

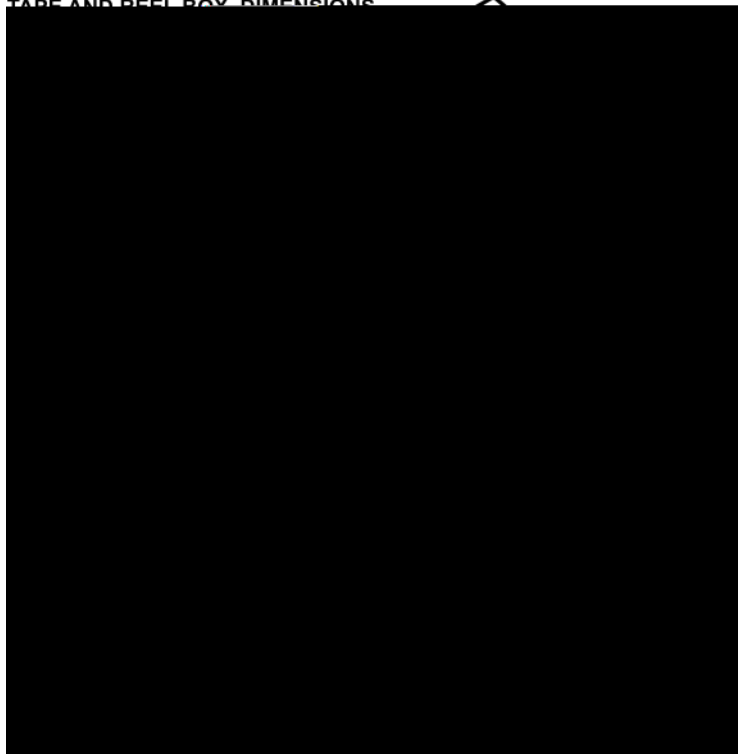
NOTE: Qualified Version Defini3002 i

## TAPE AND REEL INFORMATION



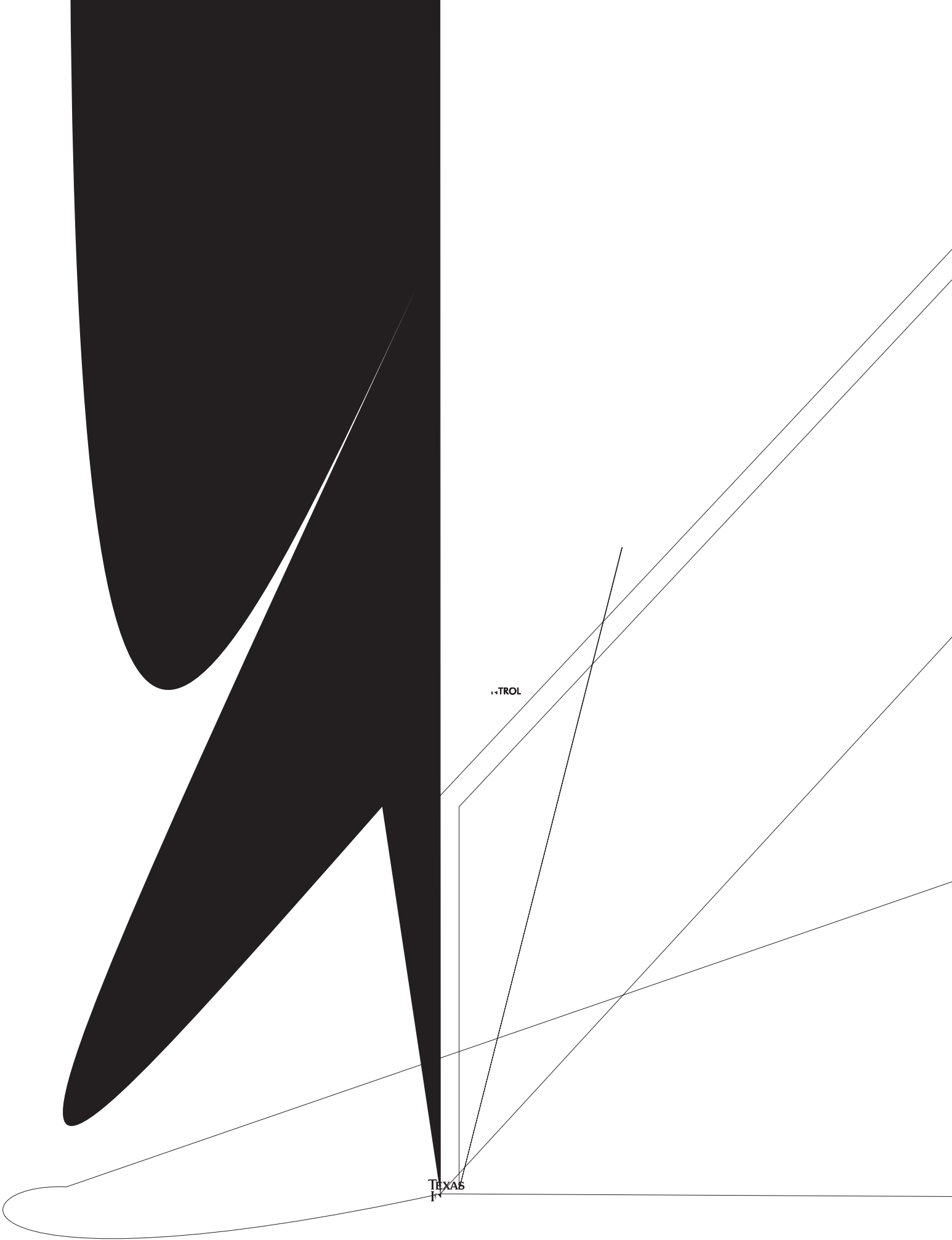
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM5112MY	MSOP-Power PAD	DGN	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM5112MY/NOPB	MSOP-Power PAD	DGN	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM5112MYX	MSOP-Power PAD	DGN	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM5112MYX/NOPB	MSOP-Power PAD	DGN	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LM5112Q1SD/NOPB	WSOP	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LM5112Q1SDX/NOPB	WSOP	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LM5112SD	WSOP	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LM5112SD/NOPB	WSOP	NGG	6	1000	178.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LM5112SDX	WSOP	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1
LM5112SDX/NOPB	WSOP	NGG	6	4500	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM5112MY	MSOP-PowerPAD	DGN	8	1000	210.0	185.0	35.0
LM5112MY/NOPB	MSOP-PowerPAD	DGN	8	1000	210.0	185.0	35.0
LM5112MYX	MSOP-PowerPAD	DGN	8	3500	367.0	367.0	35.0
LM5112MYX/NOPB	MSOP-PowerPAD	DGN	8	3500	367.0	367.0	35.0
LM5112Q1SD/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LM5112Q1SDX/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0
LM5112SD	WSON	NGG	6	1000	210.0	185.0	35.0
LM5112SD/NOPB	WSON	NGG	6	1000	210.0	185.0	35.0
LM5112SDX	WSON	NGG	6	4500	367.0	367.0	35.0
LM5112SDX/NOPB	WSON	NGG	6	4500	367.0	367.0	35.0



ENSION

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Wireless Connectivity	<a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a>

### Applications

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Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
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